



FDC637BNZ

Data Sheet

FAIRCHILD SEMICONDUCTOR FDC637BNZ MOSFET Transistor, N Channel, 6.2A, 20V, 0.021 Ω , 4.5V, 800mV

Manufacturers

ON Semiconductor, LLC

Package/Case

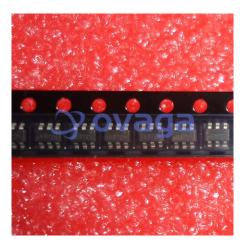
SSOT-6

Product Type

Transistors

RoHS

Green



Images are for reference only

Please submit RFQ for FDC637BNZ or Email to us: sales@ovaga.com We will contact you in 12 hours.



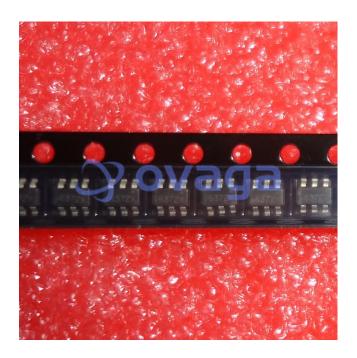
General Description

This N-Channel 2.5V specified MOSFET is produced using an advanced PowerTrench® process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance. These devices have been designed to offer exceptional power dissipation in a very small footprint compared with bigger SO-8 and TSSOP-8 packages.

Application

ONSEMI

Lifecycle



Related Products



FDC645N

ON Semiconductor, LLC SSOT-6



FDC602P

ON Semiconductor, LLC SOT163



FDB070AN06A0

ON Semiconductor, LLC TO-263



FDD3670

ON Semiconductor, LLC TO-252AA



FDC6305N

ON Semiconductor, LLC SSOT-6



FDD8647L

ON Semiconductor, LLC TO-252-3



FDD5N50NZTM

ON Semiconductor, LLC TO-252



FDD2582

ON Semiconductor, LLC TO-252AA